

## SLVE2.8K

BIDIRECTIONAL TVSarray ™

PRODUCT PREVIEW

#### DESCRIPTION

*Microsemi's proprietary process provides low standoff voltages and the lowest standby current in the industry of 0.1\muA.* This 4-pin bidirectional array is designed for use in applications where protection is required at the board level from voltage transients caused by electrostatic discharge (ESD) as defined by IEC 61000-4-2, electrical fast transients (EFT) per IEC 61000-4-4 and effects of secondary lighting.

This product is designed to provide protection in the bidirectional mode for 1 line by connecting the Input/Output line to pins 2 and 3 and pins 1 and 4 to ground. For differential protection pins 1 and 4 can be connected to a second line. The SLVE2.8K product provides board-level protection from static electricity and other induced-voltage surges that can damage sensitive circuitry.

These Transient Voltage Suppressor (TVS) diode arrays protect 2.8 V volt components such as DRAM's SRAM's CMOS, HCMOS, HSIC, and low voltage interfaces. Because of the physical size, weight and protection capabilities, this product is ideal for use in but not limited to miniaturize electronic equipment such as hand-held instruments, computers, computer peripherals and cell phones and PDA's.



TVSarray<sup>™</sup> SERIES

#### APPLICATIONS

- EIA-RS232 data rates
   19.6kbs
- EIA-RS422 data rates
   10Mbs
- EIA-RS423 data rates
   100kbs
- 200 MHz maximum

### FEATURES

- Protects 2.8 V low voltage components
- Protects 1 bidirectional line to ground or 1 differential line pair
- Bidirectional single line capacitance 50 pF
- LOW LEAKAGE 0.1 µA

SLVE2.8K

### MAXIMUM RATINGS

MAX

2.8

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C

E2.8

Peak Pulse Power 400 watts

 (24 Amps at 8/20 μs – see FIGURES 1 and 2)
 (24 Amps at 8/20 μs – see FIGURES 1 and 2)

### PACKAGING

- Tape & Reel per EIA Standard 481
  - 3,000 pieces per 7 inch reel

### MECHANICAL

- Molded SOT-143 Surface Mount
- Weight .014 grams (approximate)
- Body Marked with device number

MAX

5.3

MAX

0.1

#### **ELECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless otherwise specified** STANDBY REVERSE SNAP-BACK PUNCH-THRU CLAMPING CLAMPING (LEAKAGE) STAND-0FF VOLTAGE VOLTAGE VOLTAGE VOLTAGE CURRENT CAPACITANCE V<sub>c</sub> @ I<sub>PP</sub> = 1 Amp VOLTAGE $V_{SB}$ V<sub>PT</sub> @ 2 μA V<sub>C</sub> @ I<sub>PP</sub> = 5 Amp (f=1 MHz) PART DEVICE $I_{D}$ @ V<sub>RWM</sub> = 2.8V $I_{SB} = 50 \text{ mA}$ @ 0V NUMBER MARKING VRWM $T = 25^{\circ}C$ VOLTS VOLTS VOLTS VOLTS pF VOLTS μΑ

MIN

3.0

MAX

4.1

SLVE2.8K

www.Microsemi.com

Copyright © 2001 MSC1706.PDF 08-01 2001 REV B 8700 E. Thomas Rd. PO Box 1390, Scottsdale, AZ 85252 USA, (480) 941-6300, Fax: (480) 947-1503

MIN

2.8

MAX

100



SCOTTSDALE DIVISION

# **BIDIRECTIONAL TVSarray ™**

**PRODUCT PREVIEW** 

	SYMBOLS & DEFINITIONS
bol	DEFINITION
Μ	Rated stand off voltage: Maximum dc voltage that can be applied over the operating temperature range. Vwm must be selected to be equal or be greater than the operating voltage of the line to be protected.
т	Punch-Thru Voltage: The minimum voltage the device will exhibit at a specified current.
в	Snap-Back Voltage: The minimum snap back voltage the device will exhibit at a specific current.
C	Clamping Voltage: Maximum clamping voltage across the TVS device when subjected to a given current at a pulse time of 20 µs.
)	Standby Current: Leakage current at V <sub>WM.</sub>
	Capacitance: Capacitance of the TVS as defined @ 0 volts at a frequency of 1 MHz and stated in Pico Farads.
1000	B/20 μs 400W Pulse B/20 μs 400W Pulse
100	

FIGURE 1 **Peak Pulse Power Vs Pulse Time** 





Copyright © 2001 MSC1706.PDF 08-01 2001 REV B

#### Microsemi Scottsdale Division 8700 E. Thomas Rd. PO Box 1390, Scottsdale, AZ 85252 USA, (480) 941-6300, Fax: (480) 947-1503

# SLVE2.8K

Page 2